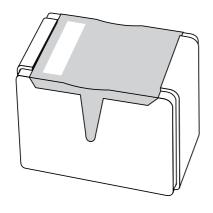
### **DISCRETE SEMICONDUCTORS**

## DATA SHEET



# **BZX284 series**Voltage regulator diodes

Product specification Supersedes data of 1999 Apr 19 2002 May 28





### Voltage regulator diodes

### **BZX284** series

#### **FEATURES**

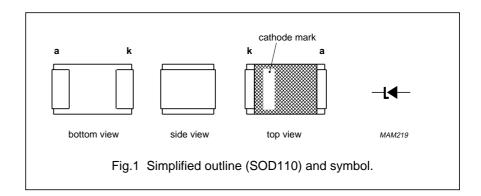
- Total power dissipation: max. 400 mW
- Two tolerance series: ±2% and ±5%
- Working voltage range: nom. 2.4 to 75 V (E24 range).

### **APPLICATIONS**

· General regulation functions.

#### **DESCRIPTION**

Low-power voltage regulator diodes in a SOD110 very small ceramic SMD package. The diodes are available in the normalized E24  $\pm 2\%$  (BZX284-B) and  $\pm 5\%$  (BZX284-C) tolerance range. The series consists of 37 types with nominal working voltages from 2.4 to 75 V.



#### **MARKING**

TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE	TYPE NUMBER	MARKING CODE
BZX284-B2V4	WO	BZX284-B15	XH	BZX284-C2V4	YO	BZX284-C15	ZH
BZX284-B2V7	WP	BZX284-B16	XI	BZX284-C2V7	YP	BZX284-C16	ZI
BZX284-B3V0	WQ	BZX284-B18	XJ	BZX284-C3V0	YQ	BZX284-C18	ZJ
BZX284-B3V3	WR	BZX284-B20	XK	BZX284-C3V3	YR	BZX284-C20	ZK
BZX284-B3V6	WS	BZX284-B22	XL	BZX284-C3V6	YS	BZX284-C22	ZL
BZX284-B3V9	WT	BZX284-B24	XM	BZX284-C3V9	YT	BZX284-C24	ZM
BZX284-B4V3	WU	BZX284-B27	XN	BZX284-C4V3	YU	BZX284-C27	ZN
BZX284-B4V7	WV	BZX284-B30	ХО	BZX284-C4V7	YV	BZX284-C30	ZO
BZX284-B5V1	WW	BZX284-B33	XP	BZX284-C5V1	YW	BZX284-C33	ZP
BZX284-B5V6	WX	BZX284-B36	XQ	BZX284-C5V6	YX	BZX284-C36	ZQ
BZX284-B6V2	WY	BZX284-B39	XR	BZX284-C6V2	YY	BZX284-C39	ZR
BZX284-B6V8	WZ	BZX284-B43	XS	BZX284-C6V8	YZ	BZX284-C43	ZS
BZX284-B7V5	XA	BZX284-B47	XT	BZX284-C7V5	ZA	BZX284-C47	ZT
BZX284-B8V2	XB	BZX284-B51	XU	BZX284-C8V2	ZB	BZX284-C51	ZU
BZX284-B9V1	XC	BZX284-B56	XV	BZX284-C9V1	ZC	BZX284-C56	ZV
BZX284-B10	XD	BZX284-B62	XW	BZX284-C10	ZD	BZX284-C62	ZW
BZX284-B11	XE	BZX284-B68	XX	BZX284-C11	ZE	BZX284-C68	ZX
BZX284-B12	XF	BZX284-B75	XY	BZX284-C12	ZF	BZX284-C75	ZY
BZX284-B13	XG	_	_	BZX284-C13	ZG	_	_

### Voltage regulator diodes

BZX284 series

### **LIMITING VALUES**

In accordance with the Absolute Maximum Rating System (IEC 60134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
I <sub>F</sub>	continuous forward current		_	250	mA
I <sub>ZSM</sub>	non-repetitive peak reverse current	t <sub>p</sub> = 100 μs; square wave; T <sub>amb</sub> = 25 °C prior to surge	see Tables		
P <sub>tot</sub>	total power dissipation	T <sub>amb</sub> = 25 °C; note 1	_	400	mW
T <sub>stg</sub>	storage temperature		-65	+150	°C
Tj	junction temperature		_	150	°C

### Note

1. Device mounted on a printed-circuit board:  $11 \times 25 \times 1.6$  mm.

### **ELECTRICAL CHARACTERISTICS**

### Total BZX284-B and BZX284-C series

 $T_j = 25$  °C unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
V <sub>F</sub>	forward voltage	I <sub>F</sub> = 10 mA; see Fig.2	0.9	V
		I <sub>F</sub> = 100 mA; see Fig.2	1.1	V
I <sub>R</sub>	reverse current			
	BZX284-B/C2V4	V <sub>R</sub> = 1 V	50	μΑ
	BZX284-B/C2V7	V <sub>R</sub> = 1 V	20	μΑ
	BZX284-B/C3V0	V <sub>R</sub> = 1 V	10	μΑ
	BZX284-B/C3V3	V <sub>R</sub> = 1 V	5	μΑ
	BZX284-B/C3V6	V <sub>R</sub> = 1 V	5	μΑ
	BZX284-B/C3V9	V <sub>R</sub> = 1 V	3	μΑ
	BZX284-B/C4V3	V <sub>R</sub> = 1 V	3	μΑ
	BZX284-B/C4V7	V <sub>R</sub> = 2 V	3	μΑ
	BZX284-B/C5V1	V <sub>R</sub> = 2 V	2	μΑ
	BZX284-B/C5V6	V <sub>R</sub> = 2 V	1	μΑ
	BZX284-B/C6V2	V <sub>R</sub> = 4 V	3	μΑ
	BZX284-B/C6V8	$V_R = 4 V$	2	μΑ
	BZX284-B/C7V5	V <sub>R</sub> = 5 V	1	μΑ
	BZX284-B/C8V2	V <sub>R</sub> = 5 V	700	nA
	BZX284-B/C9V1	V <sub>R</sub> = 6 V	500	nA
	BZX284-B/C10	V <sub>R</sub> = 7 V	200	nA
	BZX284-B/C11	V <sub>R</sub> = 8 V	100	nA
	BZX284-B/C12	V <sub>R</sub> = 8 V	100	nA
	BZX284-B/C13	V <sub>R</sub> = 8 V	100	nA
	BZX284-B/C15 to 75	$V_R = 0.7V_{Znom}$	50	nA

Voltage regulator diodes

BZX284 series

Table 1 Per type BZX284-B/C2V4 to B/C24

T<sub>j</sub> = 25 °C unless otherwise specified.

BZX284- Bxxx	WORKING VOLTAGE  V <sub>Z</sub> (V)  at I <sub>Ztest</sub> = 5 mA			DIFF		L RESIST (Ω)	ANCE	TEMP. COEFF. S <sub>Z</sub> (mV/K) at I <sub>Ztest</sub> = 5 mA	DIODE CAP.  C <sub>d</sub> (pF)  at f = 1 MHz;	NON-REPETITIVE PEAK REVERSE CURRENT I <sub>ZSM</sub> (A) at t <sub>p</sub> = 100 μs;		
Cxxx	Tol. ±	2% (B)	Tol. ±	5% (C)	at I <sub>Ztest</sub>	= 1 mA	at I <sub>Ztest</sub>	= 5 mA	(see Figs 3 and 4)	V <sub>R</sub> = 0 V	T <sub>amb</sub> = 25 °C	
	MIN.	MAX.	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.	TYP.	MAX.	MAX.	
2V4	2.35	2.45	2.2	2.6	275	400	70	100	-1.6	450	12.0	
2V7	2.65	2.75	2.5	2.9	300	450	75	100	-2.0	440	12.0	
3V0	2.94	3.06	2.8	3.2	325	500	80	95	-2.1	425	12.0	
3V3	3.23	3.37	3.1	3.5	350	500	85	95	-2.4	410	12.0	
3V6	3.53	3.67	3.4	3.8	375	500	85	90	-2.4	390	12.0	
3V9	3.82	3.98	3.7	4.1	400	500	85	90	-2.5	370	12.0	
4V3	4.21	4.39	4.0	4.6	410	600	80	90	-2.5	350	12.0	
4V7	4.61	4.79	4.4	5.0	425	500	50	80	-1.4	325	12.0	
5V1	5.00	5.20	4.8	5.4	400	480	40	60	-0.8	300	12.0	
5V6	5.49	5.71	5.2	6.0	80	400	15	40	1.2	275	12.0	
6V2	6.08	6.32	5.8	6.6	40	150	6	10	2.3	250	12.0	
6V8	6.66	6.94	6.4	7.2	30	80	6	15	3.0	215	12.0	
7V5	7.35	7.65	7.0	7.9	15	80	2	10	4.0	170	4.0	
8V2	8.04	8.36	7.7	8.7	20	80	2	10	4.6	150	4.0	
9V1	8.92	9.28	8.5	9.6	20	100	2	10	5.5	120	3.0	
10	9.80	10.20	9.4	10.6	20	150	2	10	6.4	110	3.0	
11	10.80	11.20	10.4	11.6	25	150	2	10	7.4	108	2.5	
12	11.80	12.20	11.4	12.7	25	150	2	10	8.4	105	2.5	
13	12.70	13.30	12.4	14.1	25	170	2	10	9.4	103	2.5	
15	14.70	15.30	13.8	15.6	25	200	3	15	11.4	99	2.0	
16	15.70	16.30	15.3	17.1	25	200	4	20	12.4	97	1.5	
18	17.60	18.40	16.8	19.1	25	225	4	20	14.4	93	1.5	
20	19.60	20.40	18.8	21.2	30	225	4	20	16.4	88	1.5	
22	21.60	22.40	20.8	23.3	30	250	5	25	18.4	84	1.25	
24	23.50	24.50	22.8	25.6	30	250	6	30	20.4	80	1.25	

Voltage regulator diodes

BZX284 series

Table 2Per type BZX284-B/C27 to B/C75

T<sub>i</sub> = 25 °C unless otherwise specified.

BZX284- Bxxx	WORKING VOLTAGE  V <sub>Z</sub> (V)  at I <sub>Ztest</sub> = 2 mA				DIFFE	ERENTIAI r <sub>dif</sub>	_ RESIST (Ω)	ANCE	TEMP. COEFF. S <sub>Z</sub> (mV/K) at I <sub>Ztest</sub> = 2 mA	DIODE CAP.  C <sub>d</sub> (pF)  at f = 1 MHz;	NON-REPETITIVE PEAR REVERSE CURRENT $I_{ZSM}$ (A) at $t_p$ = 100 $\mu$ s;	
Cxxx	Tol. ±	2% (B)	Tol. ±	5% (C)	at I <sub>Ztest</sub> = 0.5 mA at I <sub>Ztest</sub> = 2 mA			= 2 mA		V <sub>R</sub> = 0 V	T <sub>amb</sub> = 25 °C	
	MIN.	MAX.	MIN.	MAX.	TYP.	MAX.	TYP.	MAX.	TYP.	MAX.	MAX.	
27	26.50	27.50	25.1	28.9	35	250	8	40	23.4	73	1.0	
30	29.40	30.60	28.0	32.0	35	250	10	40	26.6	66	1.0	
33	32.30	33.70	31.0	35.0	40	275	11	40	29.7	60	0.9	
36	35.30	36.70	34.0	38.0	40	300	15	60	33.0	59	0.8	
39	38.20	39.80	37.0	41.0	40	300	25	75	36.4	58	0.7	
43	42.10	43.90	40.0	46.0	45	325	30	80	41.2	56	0.6	
47	46.10	47.90	44.0	50.0	45	325	30	90	46.1	55	0.5	
51	50.00	52.00	48.0	54.0	45	350	35	110	51.0	52	0.4	
56	54.90	57.10	52.0	60.0	50	375	40	120	57.0	49	0.3	
62	60.80	63.20	58.0	66.0	60	400	50	140	64.4	44	0.3	
68	66.60	69.40	64.0	72.0	75	400	55	160	71.7	40	0.25	
75	73.50	76.50	70.0	79.0	85	400	70	175	80.2	35	0.2	

### Voltage regulator diodes

BZX284 series

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
R <sub>th j-a</sub>	thermal resistance from junction to ambient	note 1	315	K/W

#### Note

1. Device mounted on a printed-circuit board:  $11 \times 25 \times 1.6$  mm.

### **GRAPHICAL DATA**

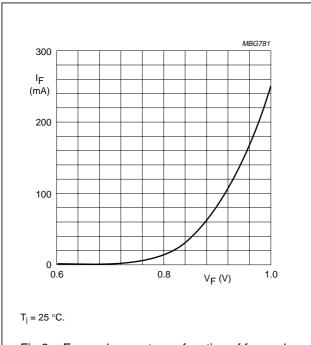


Fig.2 Forward current as a function of forward voltage; typical values.

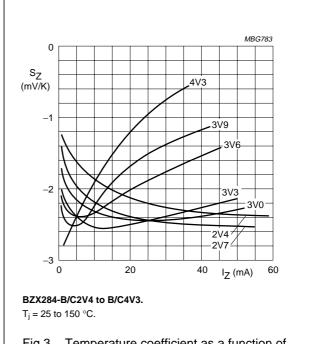
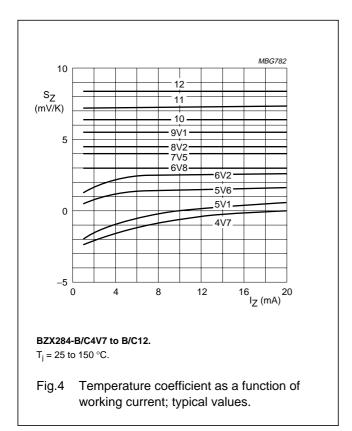


Fig.3 Temperature coefficient as a function of working current; typical values.

### Voltage regulator diodes

BZX284 series



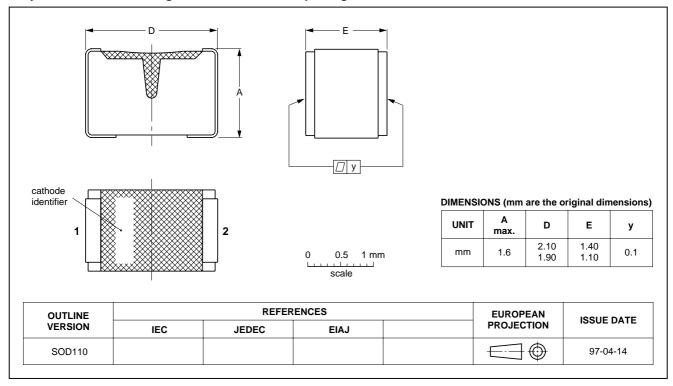
### Voltage regulator diodes

### BZX284 series

### **PACKAGE OUTLINE**

### Very small ceramic rectangular surface mounted package

#### SOD110



### Voltage regulator diodes

BZX284 series

#### **DATA SHEET STATUS**

DATA SHEET STATUS(1)	PRODUCT STATUS <sup>(2)</sup>	DEFINITIONS
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Changes will be communicated according to the Customer Product/Process Change Notification (CPCN) procedure SNW-SQ-650A.

#### **Notes**

- 1. Please consult the most recently issued data sheet before initiating or completing a design.
- 2. The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

### **DEFINITIONS**

**Short-form specification** — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

### **DISCLAIMERS**

Life support applications — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes, without notice, in the products, including circuits, standard cells, and/or software, described or contained herein in order to improve design and/or performance. Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no licence or title under any patent, copyright, or mask work right to these products, and makes no representations or warranties that these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

### Voltage regulator diodes

BZX284 series

NOTES

### Voltage regulator diodes

BZX284 series

NOTES

### Philips Semiconductors – a worldwide company

#### **Contact information**

For additional information please visit http://www.semiconductors.philips.com. Fax: +31 40 27 24825 For sales offices addresses send e-mail to: sales.addresses@www.semiconductors.philips.com.

© Koninklijke Philips Electronics N.V. 2002

SCA74

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

613514/04/pp12

Date of release: 2002 May 28

Document order number: 9397 750 09734

Let's make things better.

Philips Semiconductors



